

# Nanopower Precision Shunt Voltage Reference

## FEATURES

- **Initial Voltage Accuracy: 0.05%**
- **Low Operating Current: 800nA**
- **Low Drift: 10ppm/°C Max**
- Less Than 1Ω Dynamic Impedance
- Available in 1.25V, 2.5V, 4.096V and 5V SO-8 Packages

## APPLICATIONS


- Portable Meters
- Precision Regulators
- A/D and D/A Converters
- Calibrators

## DESCRIPTION

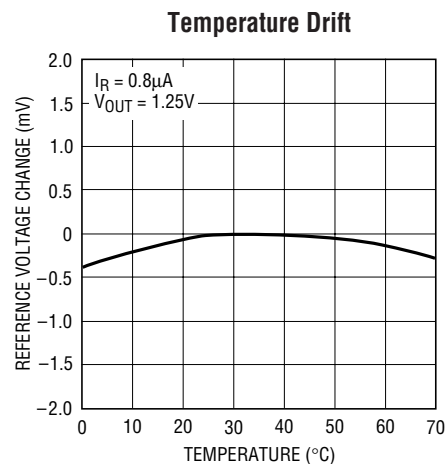
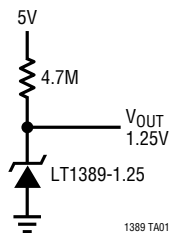
The LT<sup>®</sup>1389 is a nanopower, precision shunt voltage reference. The bandgap reference uses trimmed precision thin-film resistors and improved curvature correction techniques to achieve 0.05% initial voltage accuracy with guaranteed 10ppm/°C maximum temperature drift. Voltage regulation is maintained to an ultralow 800nA operating current. Advances in design, processing and packaging achieve low temperature cycling hysteresis.

The LT1389 does not require an output compensation capacitor, but is stable with capacitive loads. Low dynamic impedance makes the LT1389 reference easy to use from unregulated supplies.

The LT1389 reference can be used as a high performance upgrade to the LM185/LM385, LT1004, LT1034 and LT1634 where lowest power and guaranteed temperature drift are required.

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## TYPICAL APPLICATION



## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Operating Current	
1.25V .....	20mA
2.5V .....	20mA
4.096V .....	10mA
5V .....	10mA
Forward Current .....	20mA
Operating Temperature Range .....	0°C to 70°C
Storage Temperature Range (Note 2) ...	-65°C to 150°C
Lead Temperature (Soldering, 10 sec).....	300°C

## PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER	
	LT1389ACS8-1.25 LT1389BCS8-1.25 LT1389BCS8-2.5 LT1389BCS8-4.096 LT1389BCS8-5	
	S8 PART MARKING	
	389A12	1389B4
	389B12	1389B5
	389B25	

\*Connected internally. Do Not Connect external circuitry to these pins. Consult factory for Industrial and Military grade parts.

## AVAILABLE OPTIONS

TEMPERATURE	OUTPUT VOLTAGE	ACCURACY (%)	TEMPERATURE COEFFICIENT (ppm/°C)	PART TYPE	PART MARKING
0°C to 70°C	1.250	0.05	10	LT1389ACS8-1.25	389A12
	1.250	0.05	20	LT1389BCS8-1.25	389B12
	2.500	0.05	20	LT1389BCS8-2.5	389B25
	4.096	0.075	50	LT1389BCS8-4.096	1389B4
	5.000	0.075	50	LT1389BCS8-5	1389B5

## 1.25V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389ACS8/LT1389BCS8 ( $I_R = 0.8\mu\text{A}$ )	1.24937 -0.05	1.250	1.25062 0.05	V %
	LT1389ACS8 ( $I_R = 0.8\mu\text{A}$ ) ●	1.24849 -0.12	1.250	1.25149 0.12	V %
	LT1389BCS8 ( $I_R = 0.8\mu\text{A}$ ) ●	1.24762 -0.19	1.250	1.25237 0.19	V %
Reverse Breakdown Change with Current (Note 4)	$0.8\mu\text{A} \leq I_R \leq 200\mu\text{A}$ ●		0.20 0.20	0.4 1.0	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$ ●		0.3 0.3	1.0 2.0	mV mV
Minimum Operating Current	●			0.6	$\mu\text{A}$
Temperature Coefficient	LT1389ACS8 ( $I_R = 0.8\mu\text{A}$ ) ●		4	10	ppm/°C
	LT1389BCS8 ( $I_R = 0.8\mu\text{A}$ ) ●		4	20	ppm/°C
Reverse Dynamic Impedance (Note 5)	$0.8\mu\text{A} \leq I_R \leq 2\text{mA}$ ●		0.25	0.7	$\Omega$
			0.25	1.5	$\Omega$
Low Frequency Noise (Note 6)	$I_R = 0.8\mu\text{A}, 0.1\text{Hz} \leq f \leq 10\text{Hz}$		25		$\mu\text{V}_{\text{P-P}}$

## 2.5V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 ( $I_R = 0.9\mu\text{A}$ )	2.49875 -0.05	2.500	2.50125 0.05	V %
	LT1389BCS8 ( $I_R = 0.9\mu\text{A}$ )	● 2.49525 -0.19	2.500	2.50475 0.19	V %
Reverse Breakdown Change with Current (Note 4)	$0.9\mu\text{A} \leq I_R \leq 200\mu\text{A}$	●	0.2 0.2	0.5 1.5	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.3 0.3	1.0 2.5	mV mV
Minimum Operating Current		●		0.7	$\mu\text{A}$
Temperature Coefficient	$I_R = 0.9\mu\text{A}$	●	8	20	ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$0.9\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.25	0.75	$\Omega$
		●	0.25	2	$\Omega$
Low Frequency Noise (Note 6)	$I_R = 0.9\mu\text{A}$ , $0.1\text{Hz} \leq f \leq 10\text{Hz}$		50		$\mu\text{V}_{P-P}$

## 4.096V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 ( $I_R = 1.5\mu\text{A}$ )	4.09293 -0.075	4.096	4.09907 0.075	V %
	LT1389BCS8 ( $I_R = 1.5\mu\text{A}$ )	● 4.0788 -0.42	4.096	4.1132 0.42	V %
Reverse Breakdown Change with Current (Note 4)	$1.5\mu\text{A} \leq I_R \leq 200\mu\text{A}$	●	0.2 0.2	1.5 3	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.3 0.3	4 6	mV mV
Minimum Operating Current		●		1	$\mu\text{A}$
Temperature Coefficient	$I_R = 1.5\mu\text{A}$	●	12	50	ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$1.5\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.75	2	$\Omega$
		●	0.75	3	$\Omega$
Low Frequency Noise (Note 6)	$I_R = 1.5\mu\text{A}$ , $0.1\text{Hz} \leq f \leq 10\text{Hz}$		80		$\mu\text{V}_{P-P}$

**5V ELECTRICAL CHARACTERISTICS** The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at T<sub>A</sub> = 25°C. (Note 3)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 (I <sub>R</sub> = 1.5μA)		4.99625 -0.075	5.000	5.00375 0.075	V %
	LT1389BCS8 (I <sub>R</sub> = 1.5μA)	●	4.979 -0.42	5.000	5.021 0.42	V %
Reverse Breakdown Change with Current (Note 4)	1.5μA ≤ I <sub>R</sub> ≤ 200μA	●		0.2 0.2	1.5 3	mV mV
	200μA ≤ I <sub>R</sub> ≤ 2mA	●		0.3 0.3	4 6	mV mV
Minimum Operating Current		●			1	μA
Temperature Coefficient	I <sub>R</sub> = 1.5μA	●		12	50	ppm/°C
Reverse Dynamic Impedance (Note 5)	1.5μA ≤ I <sub>R</sub> ≤ 2mA			0.75	2	Ω
		●		0.75	3	Ω
Low Frequency Noise (Note 6)	I <sub>R</sub> = 1.5μA, 0.1Hz ≤ f ≤ 10Hz			100		μV <sub>P-P</sub>

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** If the part is stored outside of the specific operating temperature range, the output may shift due to hysteresis.

**Note 3:** ESD (Electrostatic Discharge) sensitive device. Use proper ESD handling precautions.

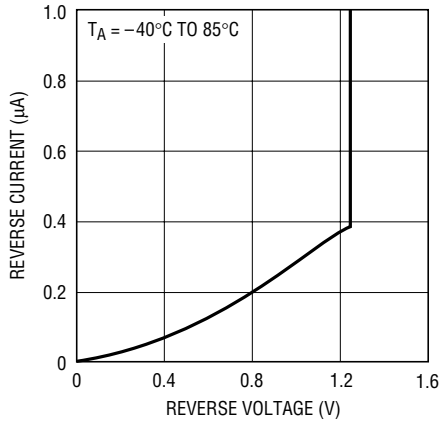
**Note 4:** Output requires 0.1μF for operating current greater than 1mA.

**Note 5:** This parameter is guaranteed by “reverse breakdown change with current” test.

**Note 6:** Peak-to-peak noise is measured with a single highpass filter at 0.1Hz and 2-pole lowpass filter at 10Hz.

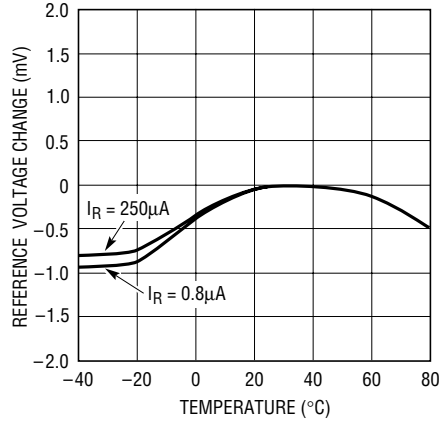
# 1.25V TYPICAL PERFORMANCE CHARACTERISTICS

**Reverse Characteristics**



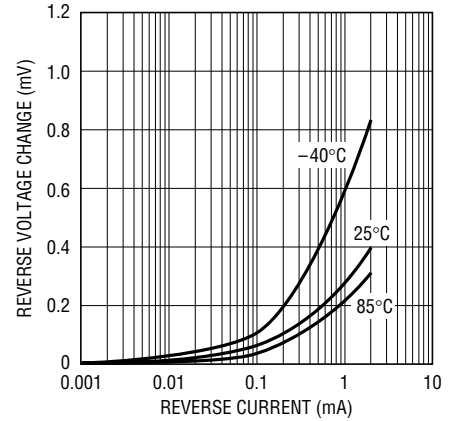
1389-1.25 G01

**Temperature Drift**



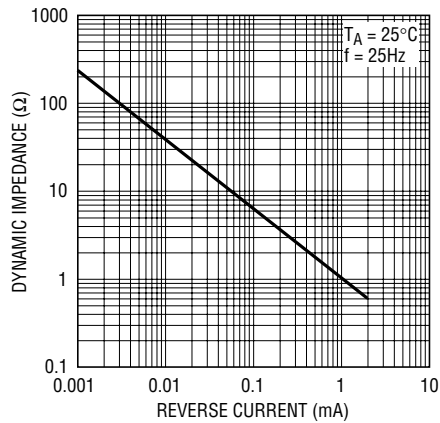
1389-1.25 G02

**Reverse Voltage Change vs Current**



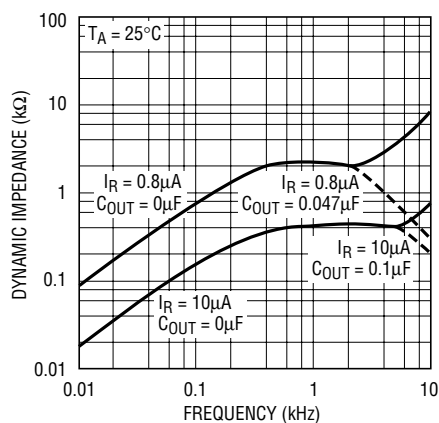
1389-1.25 G03

**Reverse Dynamic Impedance**



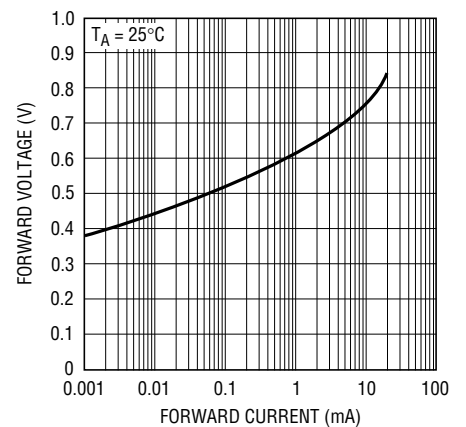
1389-1.25 G04

**Dynamic Impedance vs Frequency**



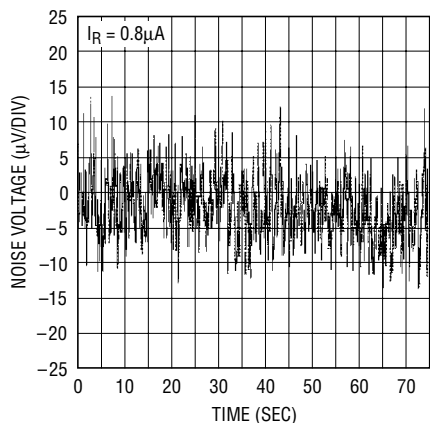
1389-1.25 G05

**Forward Characteristics**



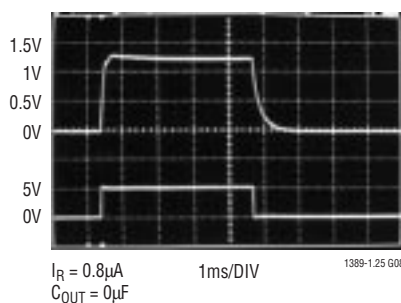
1389-1.25 G06

**0.1Hz to 10Hz Noise**



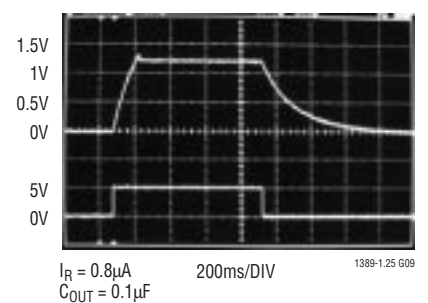
1389-1.25 G07

**Response Time**



1389-1.25 G08

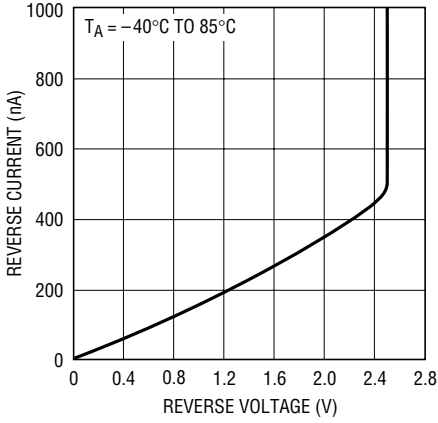
**Response Time**



1389-1.25 G09

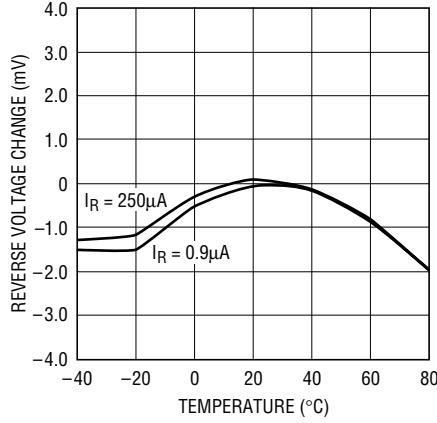
## 2.5V TYPICAL PERFORMANCE CHARACTERISTICS

Reverse Characteristics



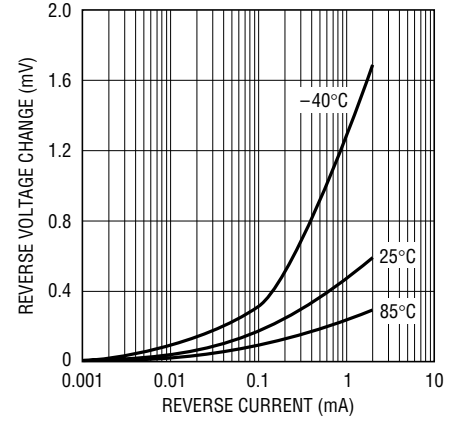
1389-2.5 G01

Temperature Drift



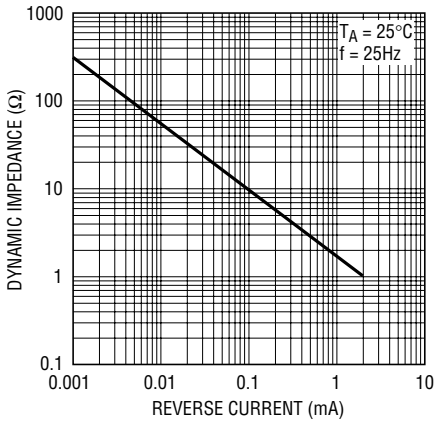
1389-2.5 TA02

Reverse Voltage Change vs Current



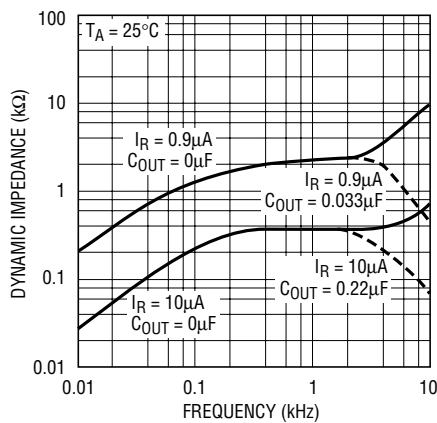
1389-2.5 G03

Reverse Dynamic Impedance



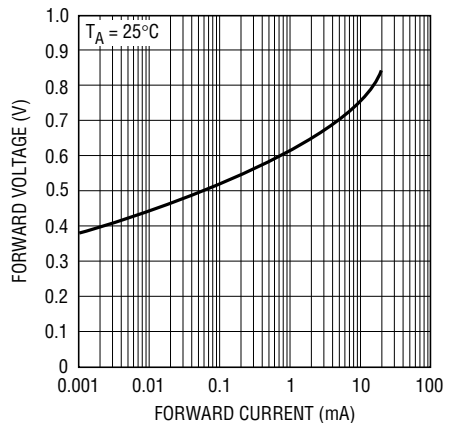
1389-2.5 G04

Dynamic Impedance vs Frequency



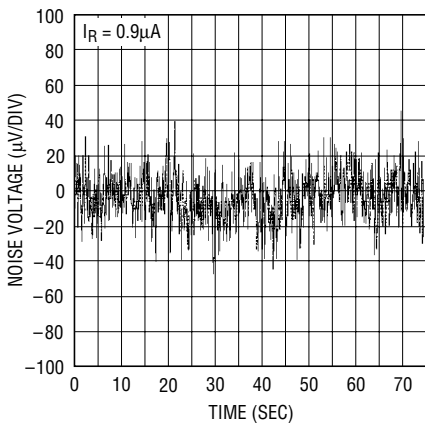
1389-2.5 G05

Forward Characteristics



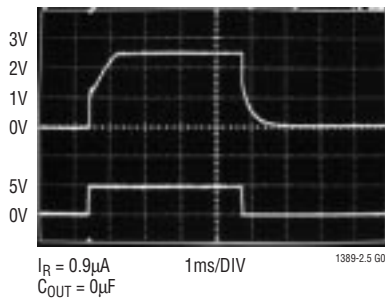
1389-2.5 G06

0.1Hz to 10Hz Noise



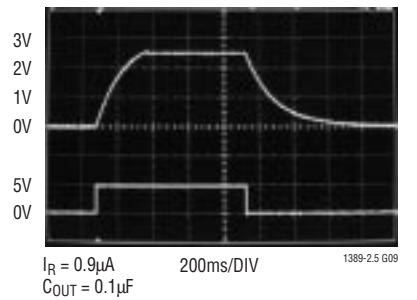
1389-2.5 G07

Response Time



1389-2.5 G08

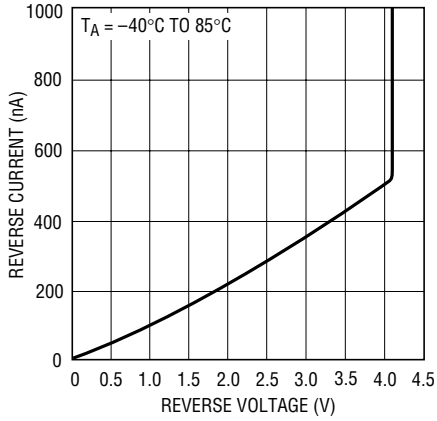
Response Time



1389-2.5 G09

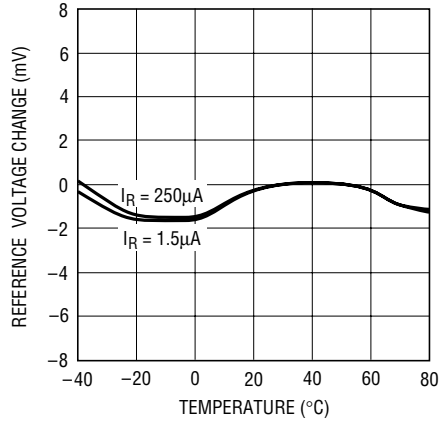
# 4.096V TYPICAL PERFORMANCE CHARACTERISTICS

**Reverse Characteristics**



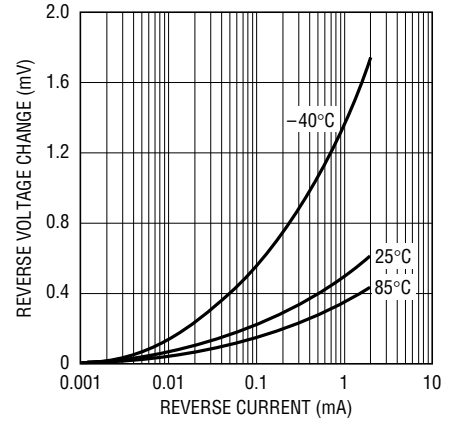
1389-4 G01

**Temperature Drift**



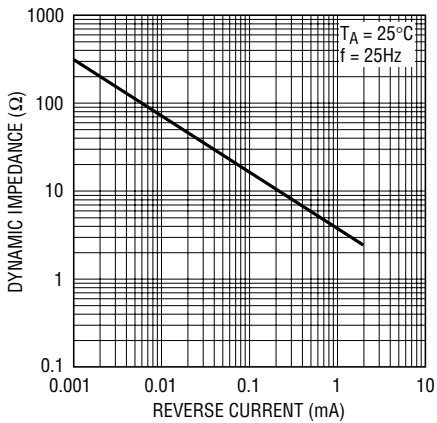
1389-4 G02

**Reverse Voltage Change vs Current**



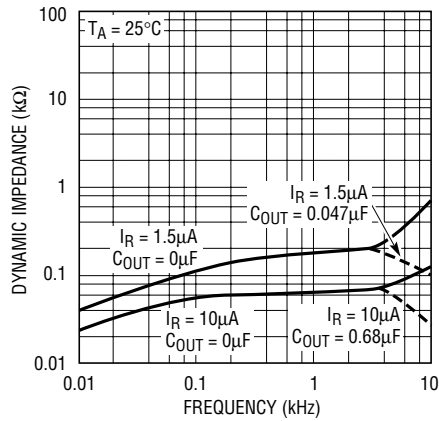
1389-4 G03

**Reverse Dynamic Impedance**



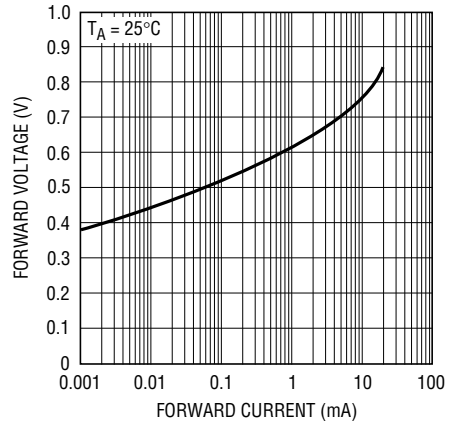
1389-4 G04

**Dynamic Impedance vs Frequency**



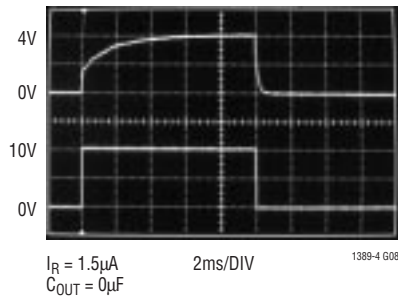
1389-4 G05

**Forward Characteristics**



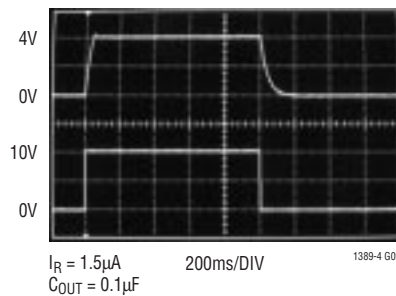
1389-4 G06

**Response Time**



1389-4 G08

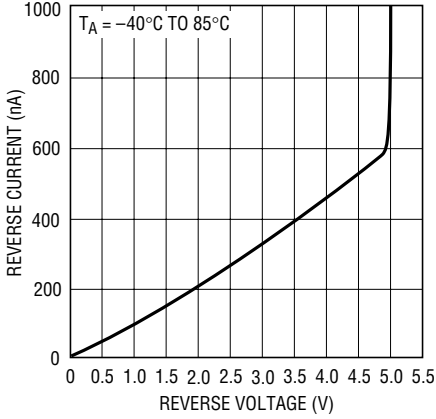
**Response Time**



1389-4 G09

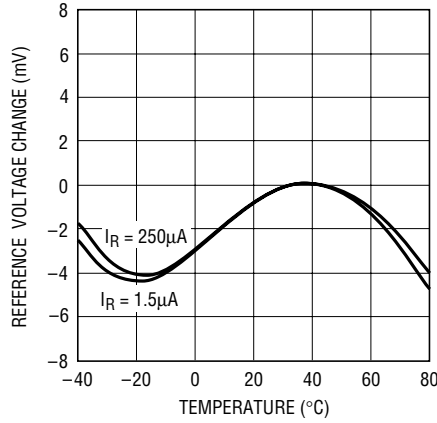
# 5V TYPICAL PERFORMANCE CHARACTERISTICS

**Reverse Characteristics**



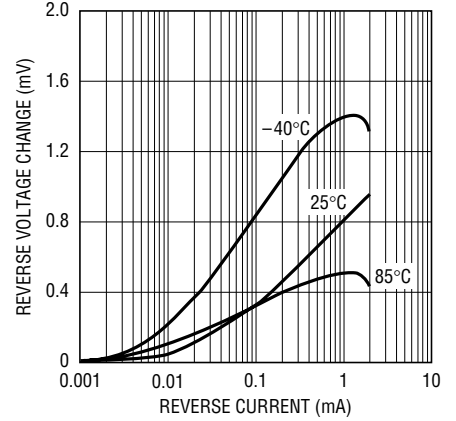
1389-4 G01

**Temperature Drift**



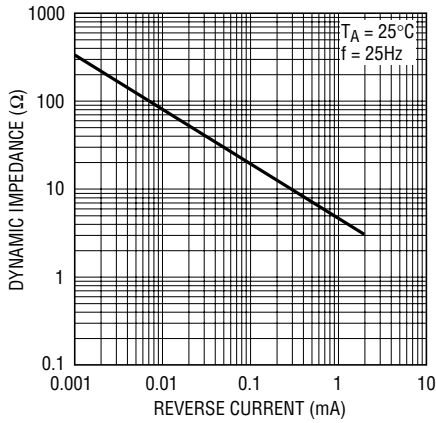
1389-5 G02

**Reverse Voltage Change vs Current**



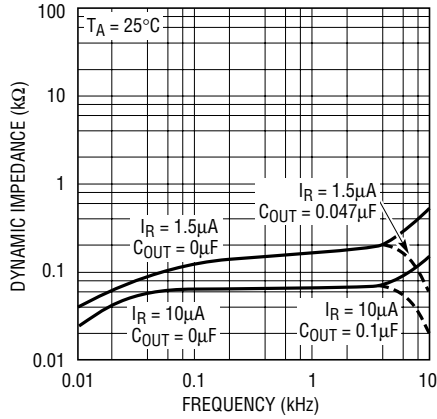
1389-4 G03

**Reverse Dynamic Impedance**



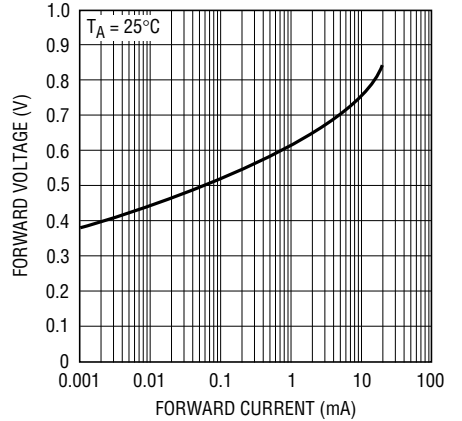
1389-5 G04

**Dynamic Impedance vs Frequency**



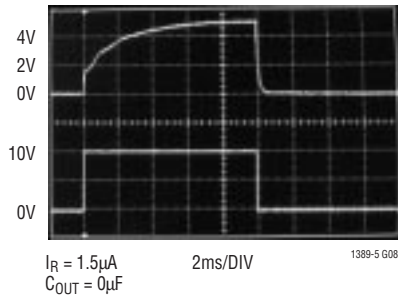
1389-4 G05

**Forward Characteristics**



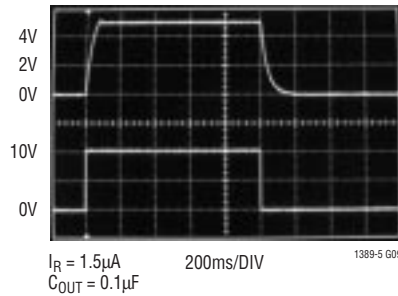
1389-5 G06

**Response Time**



1389-5 G08

**Response Time**



1389-5 G09



## APPLICATIONS INFORMATION

The reverse characteristics of the LT1389 resembles a simple resistor Zener diode parallel connection. This well behaved characteristic is important to the proper operation of circuits like Figure 1. The adjustable output voltage reference depends upon positive feedback from the LT1495's output to start-up and regulate the bias current for the LT1389. The LT1389 has no negative resistance regions that can interfere with the proper start-up of the buffered reference.

Board leakage is a concern for a nanopower precision shunt voltage reference. The LT1389 requires attention to detail in board layout in order to maximize its performance. 1.5GΩ of leakage between a DNC pin and a 5V supply will conduct 2.5nA which induces a 0.2% error in V<sub>OUT</sub>. Board leakage can be minimized by encircling the DNC pins with a guard ring operated at a potential of V<sub>OUT</sub>. By tying the guard ring to V<sub>OUT</sub> as shown in Figure 2, leakage paths are eliminated.

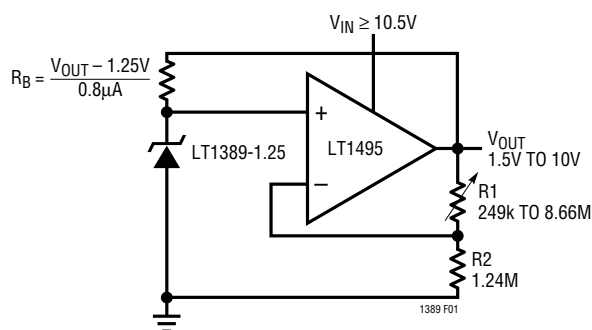


Figure 1. Adjustable Output Voltage Reference

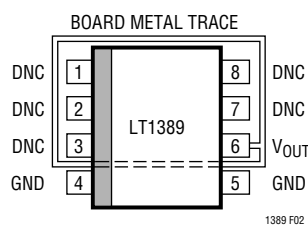
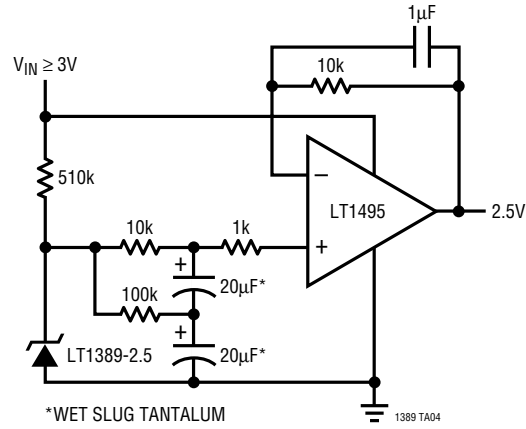


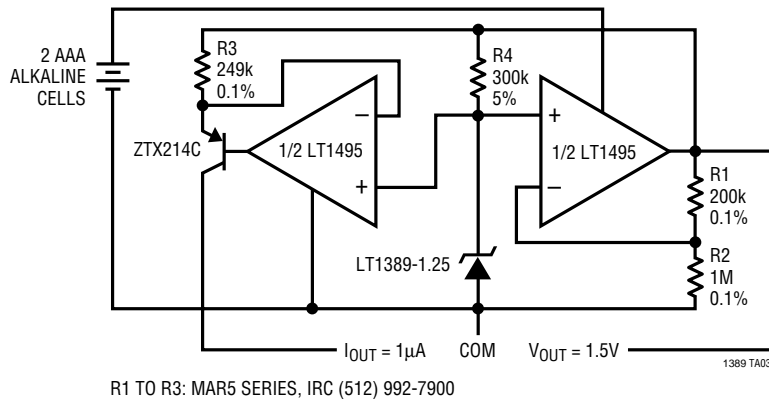
Figure 2. Guard Ring to Reduce Board Leakage

TYPICAL APPLICATIONS

2.5V Output, Low Noise Reference



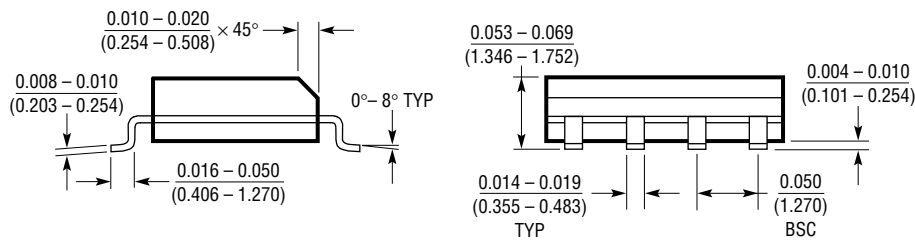
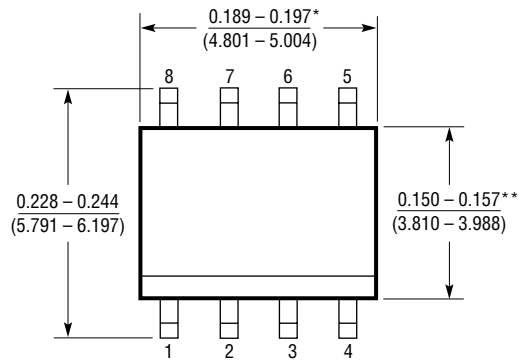
Micropower Voltage and Current Reference



**PACKAGE DESCRIPTION**

Dimensions in inches (millimeters) unless otherwise noted.

**S8 Package**  
**8-Lead Plastic Small Outline (Narrow 0.150)**  
 (LTC DWG # 05-08-1610)

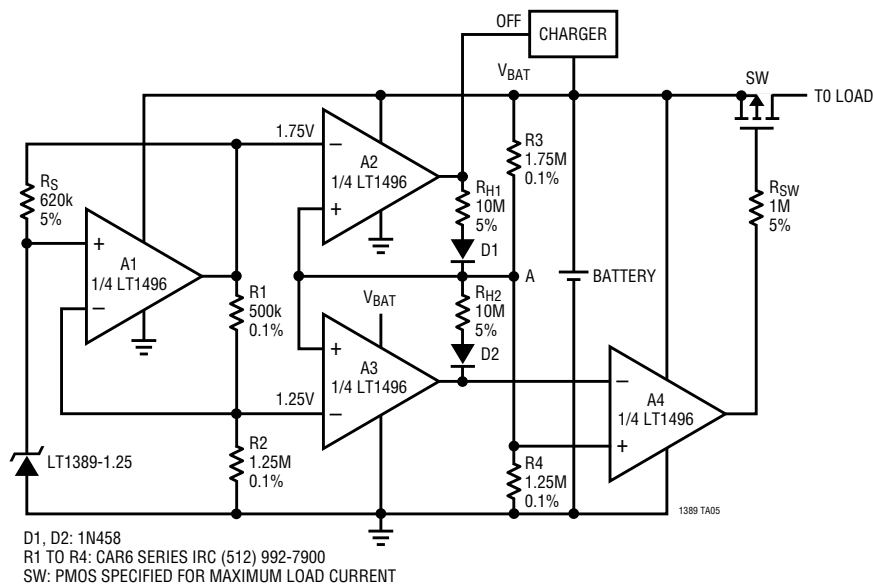


\*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE  
 \*\*DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

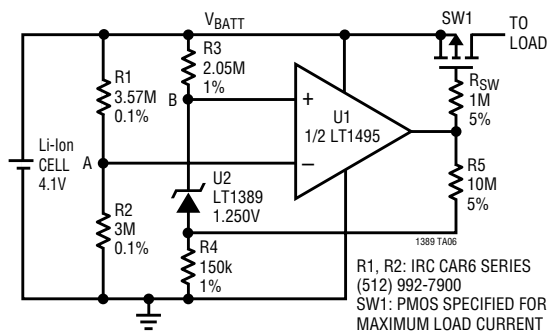
S08 1298

# TYPICAL APPLICATIONS

Single Cell Li-Ion Battery Supervisory Circuit,  $I_Q = 10\mu A$



Precision Undervoltage Lockout Circuit



## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC <sup>®</sup> 1440	Micropower Comparator with Reference	3.7 $\mu A$ Max Supply Current, 1% 1.182V Reference, MSOP, PDIP and SO-8 Packages
LT1460	Micropower Series Reference	0.075% Max, 10ppm/ $^{\circ}C$ Max Drift, 2.5V, 5V and 10V Versions, MSOP, PDIP, SO-8, SOT-23 and TO-92 Packages
LT1461	Micropower Precision LDO Series Reference	3ppm/ $^{\circ}C$ Max Drift, 0 $^{\circ}C$ to 70 $^{\circ}C$ , -40 $^{\circ}C$ to 85 $^{\circ}C$ , -40 $^{\circ}C$ to 125 $^{\circ}C$ Options in SO-8
LT1495	1.5 $\mu A$ Precision Rail-to-Rail Dual Op Amp	1.5 $\mu A$ Max Supply Current, 100pA Max $I_{OS}$
LTC1540	Nanopower Comparator with Reference	600nA Max Supply Current, 2% 1.182V Reference, MSOP and SO-8 Packages
LT1634	Micropower Precision Shunt Voltage Reference	0.05% Max, 10ppm/ $^{\circ}C$ Max Drift, 1.25V, 2.5V, 4.096V, 5V, 10 $\mu A$ Maximum Supply Current
LTC1798	6 $\mu A$ Low Dropout Series Reference	Available in Adjustable, 2.5V, 3V, 4.096V and 5V

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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